

## Single Buffer

### General Description

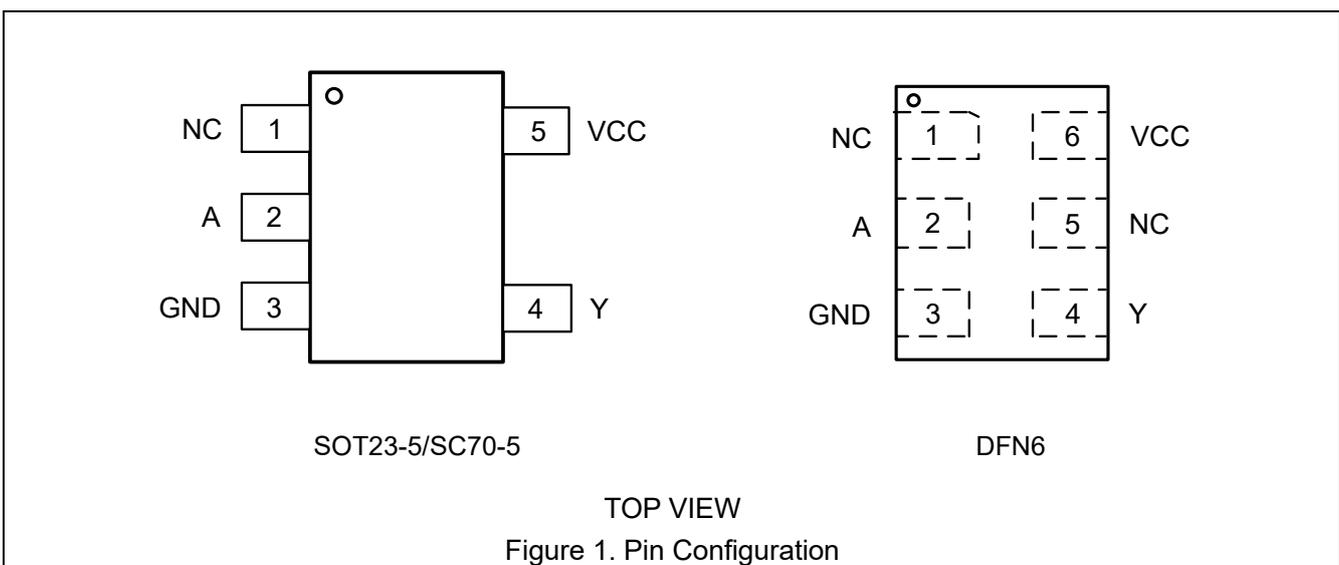
The ET74HC1G34 is a single buffer operating from a 2V to 6V supply. The device is fabricated with advanced CMOS technology to achieve ultra-high speed with high output drive, while maintaining low static power dissipation.

### Features

- Source/Sink 2mA at 4.5V
- Over-Voltage Tolerant Inputs
- Designed for 2V to 6V V<sub>CC</sub> Operation
- These Devices are Pb-Free and are RoHS Compliant Pin Configuration
- ESD Protection Complies with JESD22 Standard
  - HBM: ±4000V Pass (JEDEC JS-001)
  - CDM: ±1000V Pass (JEDEC JS-002)
- Latch-up Performance Exceeds ±100mA per JEDEC JESD78F
- Part No. and Package Information

Part No.	Package	Packing Option	MSL
ET74HC1G34	SC70-5 (1.3mm × 2.1mm)	Tape and Reel, 3K/Reel	Level 1
ET74HC1G34T	SOT23-5 (1.6mm × 2.9mm)	Tape and Reel, 3K/Reel	Level 3
ET74HC1G34Y	DFN6 (1.0mm × 1.5mm)	Tape and Reel, 3K/Reel	Level 1

### Pin configuration



# ET74HC1G34

## Pin Function

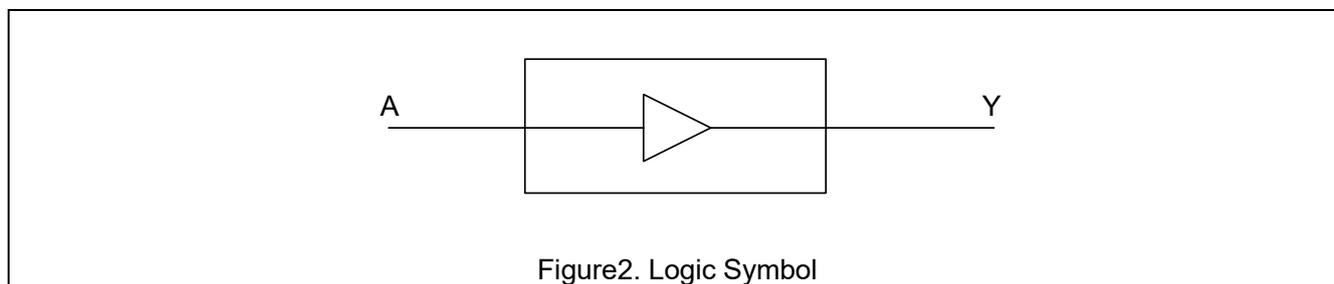
(SC70-5/ SOT23-5)

Pin No.	Pin Name	Function
1	NC	No Connect
2	A	Input
3	GND	Ground
4	Y	Output
5	VCC	Supply Voltage

DFN6

Pin No.	Pin Name	Function
1	NC	No Connect
2	A	Input
3	GND	Ground
4	Y	Output
5	NC	No Connect
6	VCC	Supply Voltage

## Block Diagram



## Function Table

Output Y = Input A	
Input A	Output Y
L	L
H	H

# ET74HC1G34

## Absolute Maximum Ratings

Symbol	Parameter		Value	Unit
V <sub>CC</sub>	DC Supply Voltage(VCC Pin)		-0.5 to 7.0	V
V <sub>I</sub>	DC Input Voltage <sup>(1)</sup>		-0.5 ≤ V <sub>I</sub> ≤ +7.0	V
V <sub>O</sub>	DC Output Voltage Output in Higher or Low State		-0.5 to V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	DC Input Diode Current V <sub>I</sub> < GND		-50	mA
I <sub>OK</sub>	DC Output Diode Current V <sub>O</sub> < GND, V <sub>O</sub> > V <sub>CC</sub>		±50	mA
I <sub>O</sub>	DC Output Sink Current		±50	mA
I <sub>CC</sub>	DC Supply Current Per Supply Pin		+100	mA
I <sub>GND</sub>	DC Ground Current Per Supply Pin		-100	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to 150	°C
T <sub>L</sub>	Lead Temperature, Soldering 10 Seconds		260	°C
T <sub>J</sub>	Max Junction Temperature		150	°C
V <sub>ESD</sub>	ESD Classification	Human Body Model <sup>(2)</sup>	±4000	V
		Charged Device Model <sup>(3)</sup>	±1000	
I <sub>LU</sub>	Max Latch Up Current Above V <sub>CC</sub> and GND at 125°C <sup>(4)</sup>		±100	mA

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

**Note1:** I<sub>O</sub> absolute maximum rating must be observed.

**Note2:** HBM tested per JEDEC JS-001;

**Note3:** CDM tested per JEDEC JS-002;

**Note4:** Latch Up Current Maximum Rating tested per JEDEC JESD78F.

## Thermal Characteristics

Symbol	Package	Ratings	Value	Unit
R <sub>θJA</sub>	SC70-5	Thermal Characteristics, Thermal Resistance, Junction-to-Air	300	°C/W
	SOT23-5		250	
	DFN6		440	
P <sub>D</sub>	SC70-5	Power Dissipation in Still Air at 85°C	215	mW
	SOT23-5		260	
	DFN6		150	

# ET74HC1G34

## Recommended Operating Conditions

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage Operating	2	6	V
V <sub>IN</sub>	DC Input Voltage	0	6	V
V <sub>OUT</sub>	DC Output Voltage (High or Low State)	0	6	V
T <sub>A</sub>	Operating Temperature Range	-40	125	°C

## Electrical Characteristics

### DC Electrical Characteristics

Symbol	Parameter	Condition	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			-40°C ≤ T <sub>A</sub> ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
V <sub>IH</sub>	High-Level Input Voltage		2.0	1.5			1.5		V
			4.5	3.15			3.15		
			6.0	4.2			4.2		
V <sub>IL</sub>	Low-Level Input Voltage		2.0			0.5		0.5	V
			4.5			1.35		1.35	
			6.0			1.8		1.8	
V <sub>OH</sub>	High-Level Output Voltage	I <sub>OH</sub> = -20μA	2~6	V <sub>CC</sub> - 0.1	V <sub>CC</sub>		V <sub>CC</sub> - 0.1		V
		I <sub>OH</sub> = -2mA	4.5	4.13	4.32		3.7		
		I <sub>OH</sub> = -2.6mA	6.0	5.63	5.81		5.2		
V <sub>OL</sub>	Low-Level Output Voltage	I <sub>OL</sub> = 20μA	2~6		0.0	0.1		0.1	V
		I <sub>OL</sub> = 2mA	4.5		0.15	0.33		0.4	
		I <sub>OL</sub> = 2.6mA	6.0		0.16	0.33		0.4	
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 6V or GND	0~6		±0.1			±1.0	μA
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 6V or V <sub>OUT</sub> = 6V	0			1		10	μA
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = 6V or GND	6			1		10	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

# ET74HC1G34

## AC Electrical Characteristics

$t_r = t_f = 5\text{ns}$

Symbol	Parameter	Condition	V <sub>CC</sub> (V)	T <sub>A</sub> = 25°C			-40°C ≤ T <sub>A</sub> ≤ 125°C		Unit
				Min	Typ	Max	Min	Max	
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay (Figure3 and 4)	C <sub>L</sub> = 50pF	2.0		31	121		141	ns
		C <sub>L</sub> = 50pF	4.5		11	25		29	
		C <sub>L</sub> = 15pF	5.0		9				
		C <sub>L</sub> = 50pF	6.0		10	22		25	

## Capacitance Characteristics

Symbol	Parameter	Condition	Typ	Unit
C <sub>IN</sub>	Input Capacitance	V <sub>CC</sub> = 6V, V <sub>I</sub> = 0V or V <sub>CC</sub>	5	pF
C <sub>PD</sub>	Power Dissipation Capacitance <sup>(5)</sup>	10MHz, V <sub>CC</sub> = 3.3V, V <sub>I</sub> = 0V or V <sub>CC</sub>	21	pF
		10MHz, V <sub>CC</sub> = 6V, V <sub>I</sub> = 0V or V <sub>CC</sub>	21	

**Note5.** C<sub>PD</sub> is used to determine the dynamic power dissipation (P<sub>D</sub> in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \sum(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f<sub>i</sub> = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

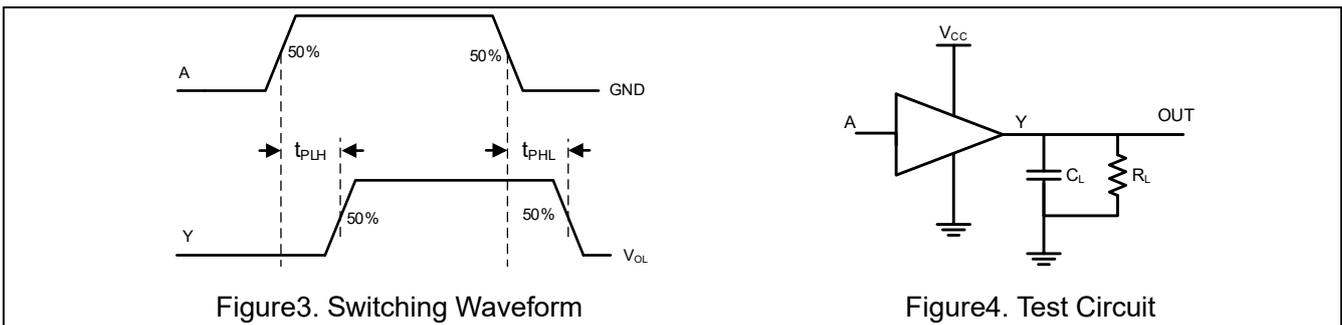
C<sub>L</sub> = output load capacitance in pF;

V<sub>CC</sub> = supply voltage in V;

N = number of inputs switching;

$\sum(C_L \times V_{CC}^2 \times f_o)$  = sum of outputs.

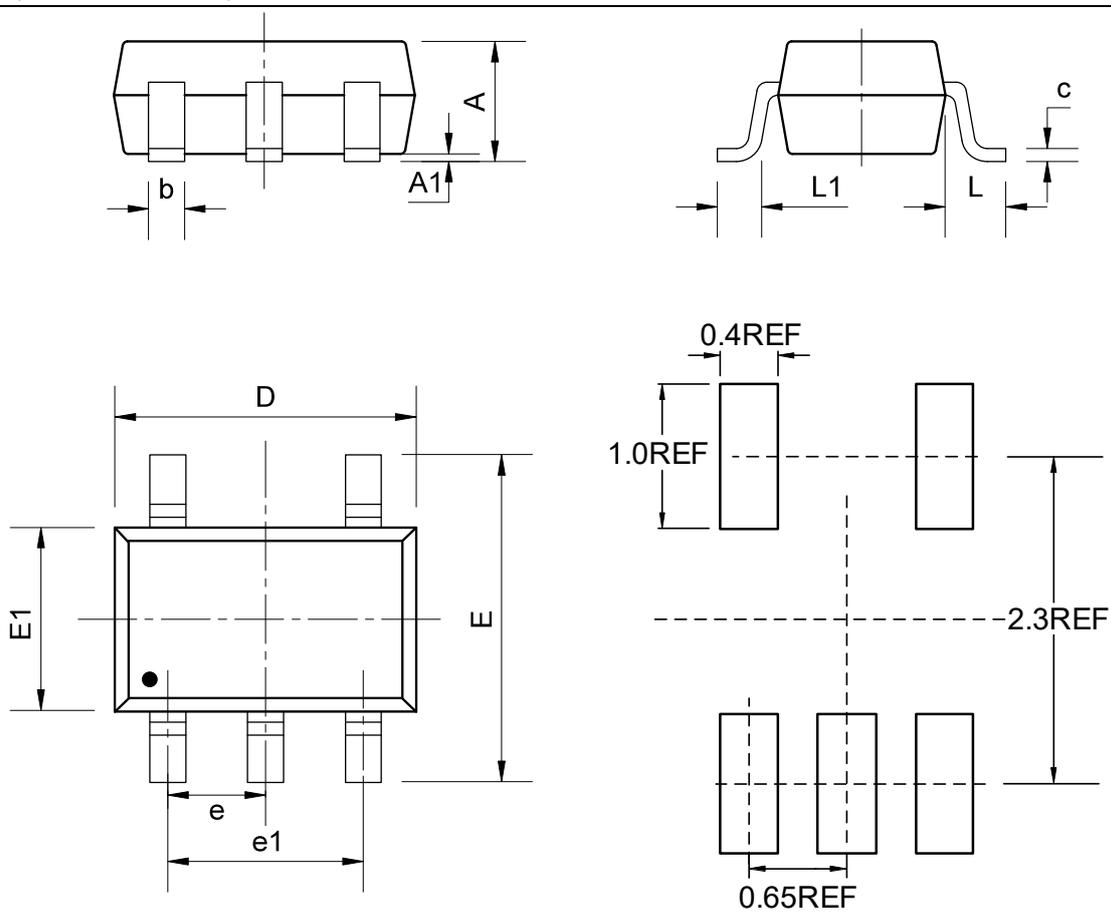
## AC Test Circuit



# ET74HC1G34

## Package Dimension

SC70-5 (1.3mm × 2.1mm)



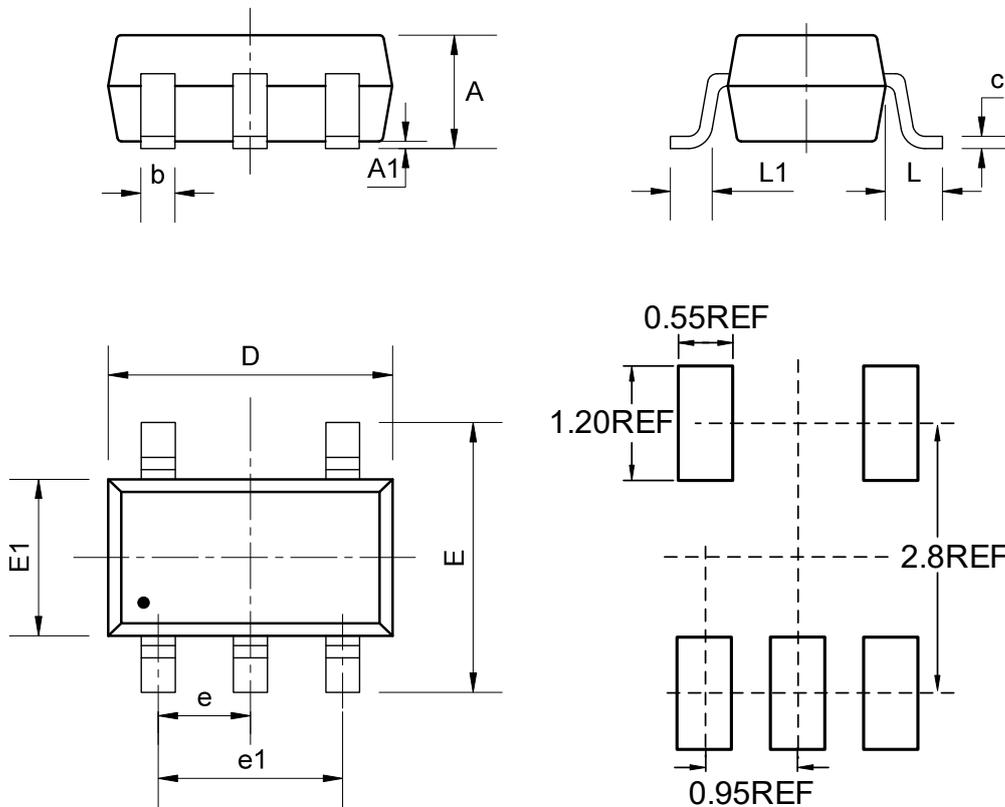
### COMMON DIMENSIONS

(Unit: mm)

SYMBOL	MIN	NOM	MAX
A	-	-	1.10
A1	0.00	-	0.15
b	0.15	-	0.35
c	0.08	-	0.20
D	2.00	2.10	2.30
e	0.65BSC		
e1	1.30BSC		
E	2.15	2.30	2.50
E1	1.15	1.30	1.45
L	0.50REF		
L1	0.33REF		

# ET74HC1G34

SOT23-5 (1.6mm × 2.9mm)



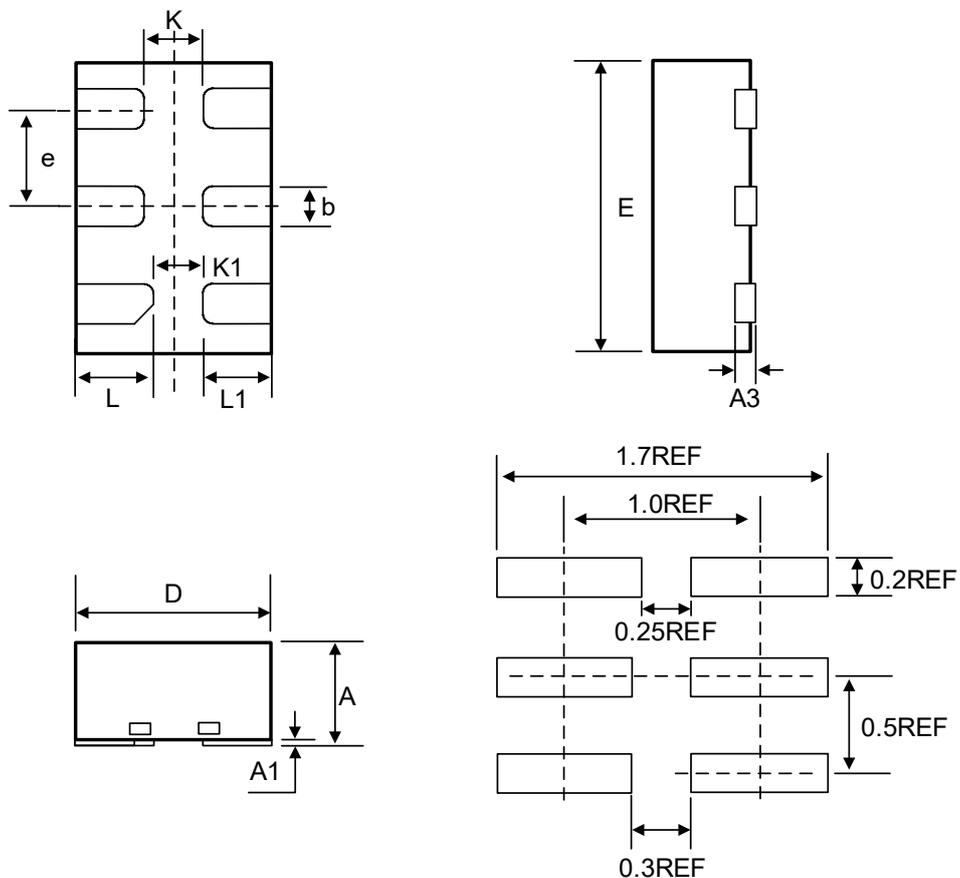
## COMMON DIMENSIONS

(Unit: mm)

SYMBOL	MIN	NOM	MAX
A	-	-	1.25
A1	0.00	-	0.15
b	0.36	-	0.50
c	0.12	-	0.20
D	2.75	2.9	3.05
e	0.90	0.95	1.00
e1	1.80	1.90	2.00
E	2.60	2.80	3.00
E1	1.45	1.6	1.75
L	0.60REF		
L1	0.30	0.45	0.60

# ET74HC1G34

DFN6 (1.0mm × 1.5mm)



## COMMON DIMENSIONS

(Unit: mm)

SYMBOL	MIN	NOM	MAX
A	0.50	--	0.60
A1	0.00	0.02	0.05
A3	0.10REF		
b	0.15	0.20	0.25
D	0.90	1.00	1.10
E	1.40	1.50	1.60
e	0.50BSC		
K	0.30REF		
K1	0.25REF		
L	0.35	0.40	0.45
L1	0.30	0.35	0.40

# ET74HC1G34

---

## Revision History and Checking Table

Version	Date	Revision Item	Modifier	Function & Spec Checking	Package & Tape Checking
1.0	2025-09-05	Official Version	Wang anran	Yang xiaoxu	Liu jiating